

Data sheet acquired from Harris Semiconductor SCHS280C

November 1997 - Revised July 2003

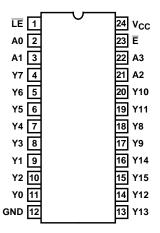
High-Speed CMOS Logic 4- to 16-Line Decoder/Demultiplexer with Input Latches

Features

- · Multifunction Capability
 - Binary to 1-of-16 Decoder
 - 1-to-16 Line Demultiplexer
- Fanout (Over Temperature Range)
- Wide Operating Temperature Range ...-55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V

Pinout

CD54HC4514 (CERDIP) CD74HC4514, CD74HC4515 (PDIP, SOIC) TOP VIEW



Description

The CD54HC4514, CD74HC4514, and CD74HC4515 are high-speed silicon gate devices consisting of a 4-bit strobed latch and a 4- to 16-line decoder. The selected output is enabled by a low on the enable input (\overline{E}). A high on \overline{E} inhibits selection of any output. Demultiplexing is accomplished by using the \overline{E} input as the data input and the select inputs (A0-A3) as addresses. This \overline{E} input also serves as a chip select when these devices are cascaded.

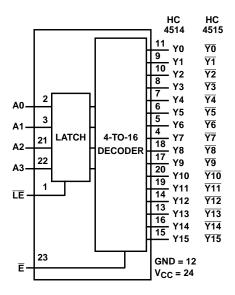
When Latch Enable ($\overline{\text{LE}}$) is high the output follows changes in the inputs (see truth table). When $\overline{\text{LE}}$ is low the output is isolated from changes in the input and remains at the level (high for the 4514, low for the 4515) it had before the latches were enabled. These devices, enhanced versions of the equivalent CMOS types, can drive 10 LSTTL loads.

Ordering Information

PART NUMBER	TEMP. RANGE (°C)	PACKAGE
CD54HC4514F3A	-55 to 125	24 Ld CERDIP
CD74HC4514E	-55 to 125	24 Ld PDIP
CD74HC4514EN	-55 to 125	24 Ld PDIP
CD74HC4514M	-55 to 125	24 Ld SOIC
CD74HC4514M96	-55 to 125	24 Ld SOIC
CD74HC4515E	-55 to 125	24 Ld PDIP
CD74HC4515EN	-55 to 125	24 Ld PDIP
CD74HC4515M	-55 to 125	24 Ld SOIC
CD74HC4515M96	-55 to 125	24 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel.

Functional Diagram



DECODE TRUTH TABLE ($\overline{LE} = 1$)

		DECODE	R INPUTS		ADDRESSED OUTPUT
ENABLE	А3	A2	A1	Α0	4514 = LOGIC 1 (HIGH) 4515 = LOGIC 0 (HIGH)
0	0	0	0	0	Yo
0	0	0	0	1	Y1
0	0	0	1	0	Y2
0	0	0	1	1	Y3
0	0	1	0	0	Y4
0	0	1	0	1	Y5
0	0	1	1	0	Y6
0	0	1	1	1	Y7
0	1	0	0	0	Y8
0	1	0	0	1	Y9
0	1	0	1	0	Y10
0	1	0	1	1	Y11
0	1	1	0	0	Y12
0	1	1	0	1	Y13
0	1	1	1	0	Y14
0	1	1	1	1	Y15
1	Х	Х	Х	Х	All Outputs = 0, 4514 All Outputs = 1, 4515

X = Don't Care; Logic 1 = High; Logic 0 = Low

 2V
 1000ns (Max)

 4.5V
 500ns (Max)

 6V
 400ns (Max)

Thermal Information

Thermal Resistance (Typical)	θ_{JA} (oC/W)
E (PDIP) Package (Note 1)	. 67
EN (PDIP) Package (Note 1)	
M (SOIC) Package (Note 2)	. 46
Maximum Junction Temperature	
Maximum Storage Temperature Range	65°C to 150°C
Maximum Lead Temperature (Soldering 10s) (SOIC - Lead Tips Only)	300°C

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTES

Input Rise and Fall Time

- 1. The package thermal impedance is calculated in accordance with JESD 51-3.
- 2. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TES CONDI		V _{CC}	25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)			TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	•											
High Level Input	V _{IH}	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	V _{IL}	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output	V _{OH}	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
Voltage CMOS Loads			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output	7		-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V

DC Electrical Specifications (Continued)

		TES CONDI		V _{CC}		25°C		-40°C T	O 85°C	-55°C T	O 125°C	
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
Low Level Output	V _{OL}	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	II	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μА
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μА

Prerequisite For Switching Specifications

		TEST	vcc		25°C		-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	•										
LE Pulse Width	t _W	-	2	75	-	-	95	-	110	-	ns
			4.5	30	-	-	19	-	22	-	ns
			6	35	-	-	16	-	19	-	ns
Select to LE Set-Up Time	t _{SU}	-	2	100	-	-	125	-	150	-	ns
			4.5	20	-	-	25	-	30	-	ns
			6	17	-	-	21	-	26	-	ns
Select to LE Hold Time	t _H	-	2	0	-	-	0	-	0	-	ns
			4.5	0	-	-	0	-	0	-	ns
			6	0	-	-	0	-	0	-	ns

Switching Specifications $C_L = 50pF$, Input t_r , $t_f = 6ns$

	TEST			25°C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	CONDITIONS	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES									-		
Propagation Delay	t _{PHL} , t _{PLH}	$C_L = 50pF$									
Select to Outputs			2	-	-	275	-	345	-	415	ns
			4.5	-	-	55	-	69	-	83	ns
		C _L = 15pF	5	-	23	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	47	-	59	-	71	ns
LE to Outputs	t _{PHL} , t _{PLH}	C _L = 50pF	2	-	-	225	-	280	-	340	ns
			4.5	-	-	45	-	56	-	68	ns
		C _L = 15pF	5	ı	19	-	i	i	-	-	ns
		C _L = 50pF	6	-	-	38	-	48	-	58	ns

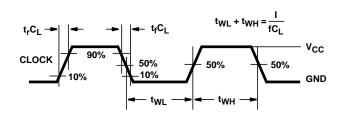
Switching Specifications $C_L = 50pF$, Input t_r , $t_f = 6ns$ (Continued)

				25°C		-40°C TO 85°C		-55°C TO 125°C			
PARAMETER	SYMBOL	TEST CONDITIONS V	L CONDITIONS V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
E to Outputs	t _{PHL} , t _{PLH}	C _L = 50pF	2	-	-	175	-	220	-	265	ns
			4.5	-	-	35	-	44	-	53	ns
		C _L = 15pF	5	-	14	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	30	-	37	-	45	ns
Output Transition Time	t _{THL} , t _{TLH}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
			4.5	-	-	15	-	19	-	22	ns
			6	-	-	13	-	16	-	19	ns
Input Capacitance	C _{IN}	C _L = 50pF	-	10	-	10	-	10	-	10	pF
Power Dissipation Capacitance (Notes 3, 4)	C _{PD}	-	5	-	70	-	-	-	-	-	pF

NOTES:

- 3. $C_{\mbox{\scriptsize PD}}$ is used to determine the dynamic power consumption, per package.
- $4. \ \ P_D = V_{CC}{}^2 \ f_i \ (C_{PD} + C_L) \ where \ f_i = Input \ Frequency, \ C_L = Output \ Load \ Capacitance, \ V_{CC} = Supply \ Voltage.$

Test Circuits and Waveforms



NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%.

FIGURE 1. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH

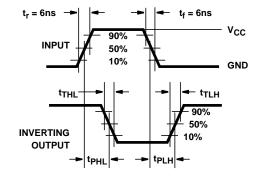


FIGURE 2. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

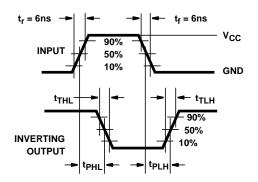


FIGURE 3. HC TRANSITION TIMES AND PROPAGATION DELAY TIMES, COMBINATION LOGIC

Test Circuits and Waveforms (Continued)

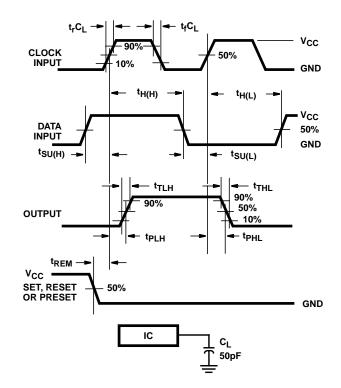


FIGURE 4. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

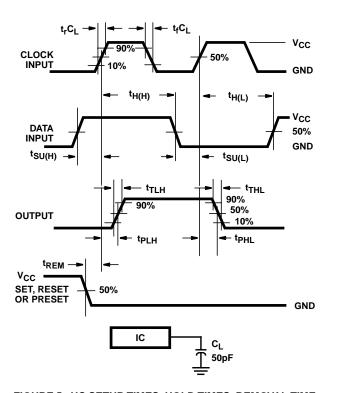


FIGURE 5. HC SETUP TIMES, HOLD TIMES, REMOVAL TIME, AND PROPAGATION DELAY TIMES FOR EDGE TRIGGERED SEQUENTIAL LOGIC CIRCUITS

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
5962-9865501QJA	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-9865501QJ A CD54HC4514F3A
CD54HC4514F3A	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-9865501QJ A CD54HC4514F3A
CD54HC4514F3A.A	Active	Production	CDIP (J) 24	15 TUBE	No	Call TI	N/A for Pkg Type	-55 to 125	5962-9865501QJ A CD54HC4514F3A
CD74HC4514M	Obsolete	Production	SOIC (DW) 24	-	-	Call TI	Call TI	-55 to 125	HC4514M
CD74HC4514M96	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4514M
CD74HC4514M96.A	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4514M
CD74HC4515M	Obsolete	Production	SOIC (DW) 24	-	-	Call TI	Call TI	-55 to 125	HC4515M
CD74HC4515M96	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4515M
CD74HC4515M96.A	Active	Production	SOIC (DW) 24	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC4515M

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF CD54HC4514, CD74HC4514:

Catalog: CD74HC4514

Military: CD54HC4514

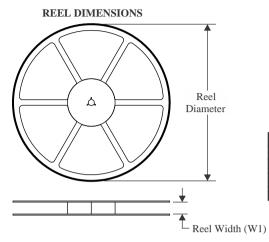
NOTE: Qualified Version Definitions:

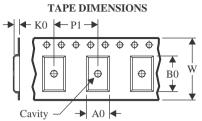
- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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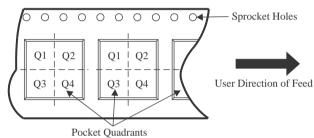
TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

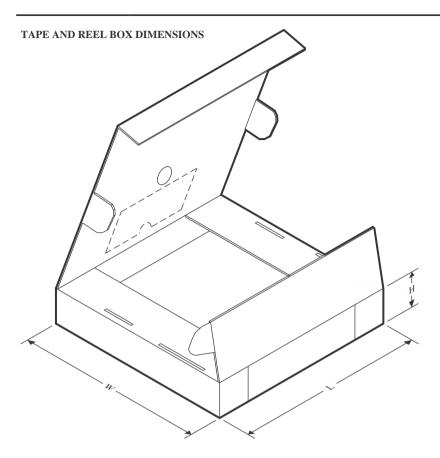
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC4514M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1
CD74HC4515M96	SOIC	DW	24	2000	330.0	24.4	10.75	15.7	2.7	12.0	24.0	Q1

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*All dimensions are nominal

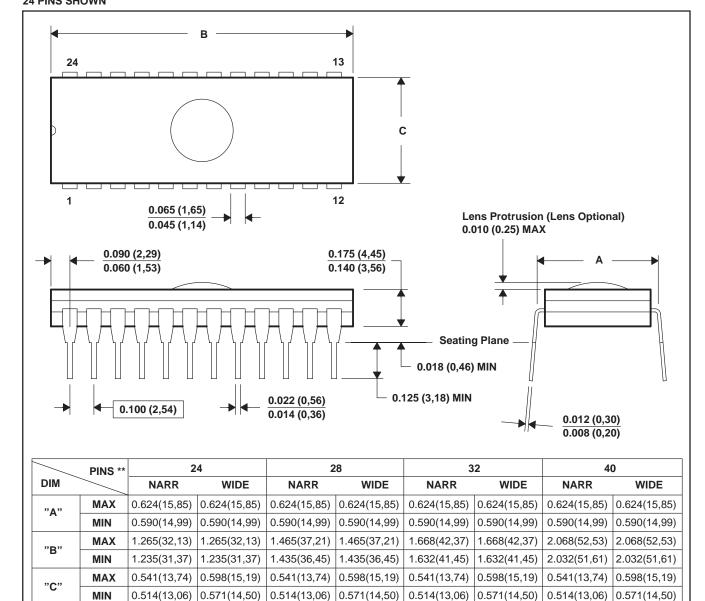
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC4514M96	SOIC	DW	24	2000	350.0	350.0	43.0
CD74HC4515M96	SOIC	DW	24	2000	350.0	350.0	43.0

4040084/C 10/97

J (R-GDIP-T**)

24 PINS SHOWN

CERAMIC DUAL-IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Window (lens) added to this group of packages (24-, 28-, 32-, 40-pin).
- D. This package can be hermetically sealed with a ceramic lid using glass frit.
- E. Index point is provided on cap for terminal identification.



DW (R-PDSO-G24)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AD.



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